

STD11N50M2

STD11N50M2 Information





Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



STD11N50M2 Specifications

Manufacturer Part Number	STD11N50M2
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-252-3, DPak (2 Leads + Tab), SC-63
Series	MDmesh? II Plus
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	500V
Current - Continuous Drain (Id) @ 25°C	8A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	395pF @ 100V
Vgs (Max)	±25V
FET Feature	-
Power Dissipation (Max)	85W (Tc)
Rds On (Max) @ Id, Vgs	530 mOhm @ 4A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	DPAK
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
	Report errors?

STD11N50M2 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

STD11N50M2 Payment Methods



STD11N50M2 Shipping Methods



If you have any question about STD11N50M2, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com